

PUB4702

Silicon N-Channel Power F-MOS FET

■ Features

- Avalanche energy capacity guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown
- Low-voltage drive
- Incorporating built-in zener diodes

■ Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

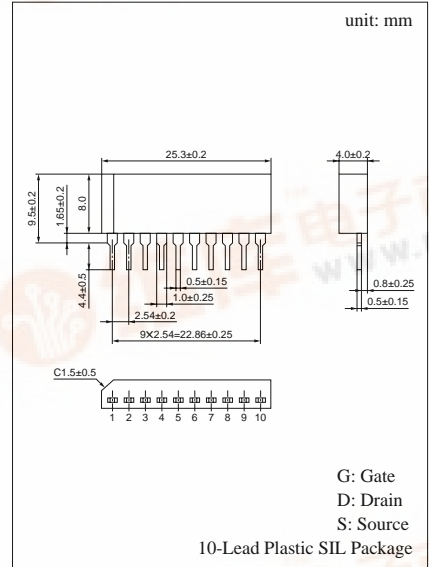
■ Absolute Maximum Ratings (T_C = 25°C)

Parameter	Symbol	Ratings	Unit	
Drain to Source breakdown voltage	V _{DSS}	35 ± 10	V	
Gate to Source voltage	V _{GSS}	±15	V	
Drain current	DC	I _D	±1	A
	Pulse	I _{DP}	±2	A
Avalanche energy capacity	EAS*	2.5	mJ	
Allowable power dissipation	T _C = 25°C	P _D	15	W
	T _a = 25°C		3.5	
Channel temperature	T _{ch}	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

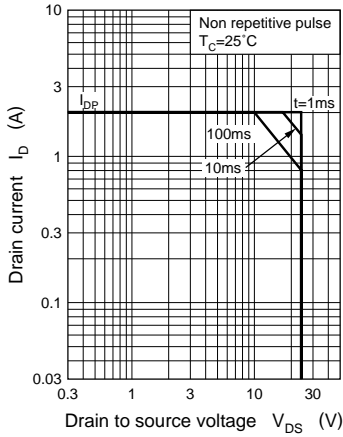
* L = 5mH, I_L = 1A, 1 pulse

■ Electrical Characteristics (T_C = 25°C)

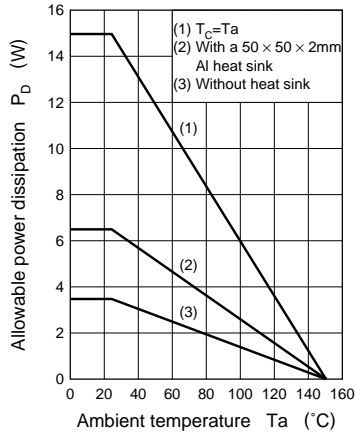
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	I _{DSS}	V _{DS} = 25V, V _{GS} = 0			10	μA
Gate to Source leakage current	I _{GSS}	V _{GS} = ±15V, V _{DS} = 0			±10	μA
Drain to Source breakdown voltage	V _{DSS}	I _D = 1mA, V _{GS} = 0	25		45	V
Gate threshold voltage	V _{th}	V _{DS} = 10V, I _D = 1mA	1		2.5	V
Drain to Source ON-resistance	R _{DS(on)1}	V _{GS} = 10V, I _D = 0.5A		220	380	mΩ
	R _{DS(on)2}	V _{GS} = 4V, I _D = 0.5A		390	680	mΩ
Forward transfer admittance	Y _{fs}	V _{DS} = 10V, I _D = 0.5A	0.6	1		S
Diode forward voltage	V _{DSF}	I _{DR} = 1A, V _{GS} = 0			-1.5	V
Input capacitance (Common Source)	C _{iss}	V _{DS} = 10V, V _{GS} = 0, f = 1MHz		135		pF
Output capacitance (Common Source)	C _{oss}			85		pF
Reverse transfer capacitance (Common Source)	C _{rss}			50		pF
Turn-on time	t _{on}	V _{GS} = 10V, I _D = 0.5A		120		ns
Fall time	t _f			390		ns
Turn-off time (delay time)	t _{d(off)}	V _{DD} = 25V, R _L = 50Ω		800		ns



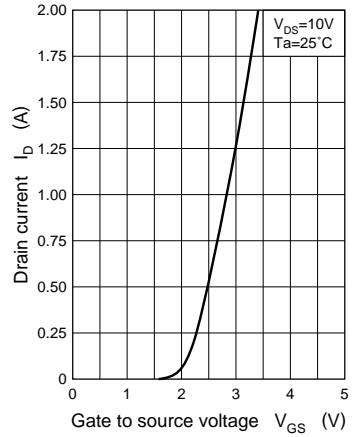
Area of safe operation (ASO)



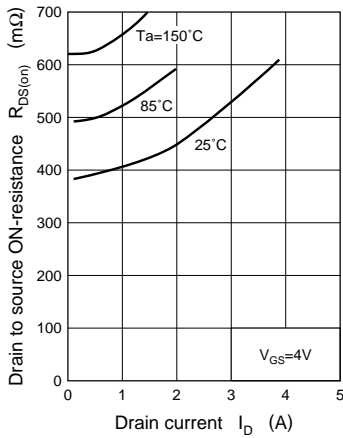
$P_D - T_a$



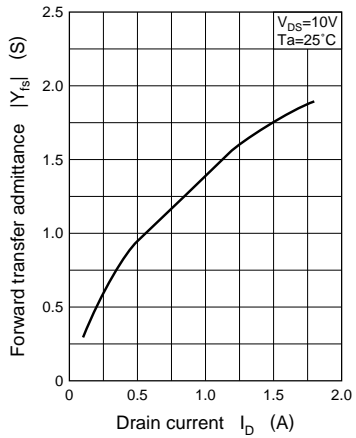
$I_D - V_{GS}$



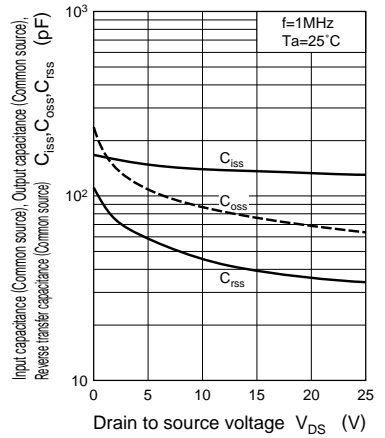
$R_{DS(on)} - I_D$



$|Y_{fs}| - I_D$



$C_{iss}, C_{oss}, C_{rss} - V_{DS}$



$R_{th(t)} - t$

